

## Description

This series of fixed-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. In addition, they can be used with power-pass elements to make high-current voltage regulators. Each of these regulators can deliver up to 100 mA of output current. The internal limiting and thermal shutdown features of these regulators make them essentially immune to overload. When used as a replacement for a Zener diode-resistor combination, an effective improvement in output impedance can be obtained together with lower-bias current.

## Features

- 3-Terminal Regulators
- Output Current Up to 100 mA
- No External Components
- Internal Thermal Overload Protection
- Internal Short-Circuit Limiting

## Package information



Package TO-92  
(top view)



## Absolute maximum ratings

over operating temperature range (unless otherwise noted)

Parameter	Maximum			Units
	MIK78L05A thru MIK78L10A	MIK78L12A thru MIK78L18A	MIK78L24A	
Input voltage	30	35	40	V
Operating free-air, case, or virtual junction temperature range	0 to 150	0 to 150	0 to 150	°C
Storage temperature range	-65 to 150	-65 to 150	-65 to 150	
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260	260	260	

## Recommended operating conditions

Parameter	Min	Max	Units	
Input voltage, $V_i$	MIK78L05A	7	20	V
	MIK78L06A	8	20	
	MIK78L08A	10.5	23	
	MIK78L09A	11.5	24	
	MIK78L10A	12.5	25	
	MIK78L12A	14.5	27	
	MIK78L15A	17.5	30	
	MIK78L18A	20.5	33	
MIK78L24A	26.5	39		
Output current, $I_o$		100	mA	
Operating virtual junction temperature, $T_J$	0	125	°C	

## Device Selection Guide

Device	Output Voltage
MIK78L05A	5 V
MIK78L06A	6 V
MIK78L08A	8 V
MIK78L09A	9 V
MIK78L10A	10 V
MIK78L12A	12 V
MIK78L15A	15 V
MIK78L18A	18 V
MIK78L24A	24 V

**Electrical characteristics MIK78L05A**

Electrical characteristics at specified virtual junction temperature,  $V_I = 10V$ ,  $I_O = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L05A			Units
			Min	Typ	Max	
Output voltage**		25°C	4.8	5	5.2	V
	$I_O = 1mA$ to 40 mA, $V_I = 7V$ to 20V	0°C to 125°C	4.75	5	5.25	
	$I_O = 1mA$ to 70mA,		4.75	5	5.25	
Input regulation	$V_I = 7V$ to 20V	25°C		32	150	mV
	$V_I = 8V$ to 20V			26	100	
Ripple rejection	$V_I = 8V$ to 18V, $f = 120Hz$	25°C	41	49		dB
Output regulation	$I_O = 1mA$ to 100mA	25°C		15	60	mV
	$I_O = 1mA$ to 40mA			8	30	
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		42		μV
Dropout voltage		25°C		1.7		V
Bias current		25°C		3.8	6	mA
		125°C			5.5	
Bias current change	$V_I = 8V$ to 20V	0°C to 125°C			1.5	
	$I_O = 1mA$ to 40mA				0.1	

**Electrical characteristics MIK78L06A**

Electrical characteristics at specified virtual junction temperature,  $V_I = 11V$ ,  $I_O = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L06A			Units
			Min	Typ	Max	
Output voltage**		25°C	5.75	6	6.25	V
	$I_O = 1mA$ to 40 mA, $V_I = 8V$ to 20V	0°C to 125°C	5.7	6	6.3	
	$I_O = 1mA$ to 70mA,		5.7	6	6.3	
Input regulation	$V_I = 8V$ to 20V	25°C		35	175	mV
	$V_I = 9V$ to 20V			29	125	
Ripple rejection	$V_I = 9V$ to 19V, $f = 120Hz$	25°C	40	48		dB
Output regulation	$I_O = 1mA$ to 100mA	25°C		16	80	mV
	$I_O = 1mA$ to 40mA			9	40	
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		46		μV
Dropout voltage		25°C		1.7		V
Bias current		25°C		3.9	6	mA
		125°C			5.5	
Bias current change	$V_I = 9V$ to 20V	0°C to 125°C			1.5	
	$I_O = 1mA$ to 40mA				0.1	

\* Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33μF capacitor across the input and a 0.1μF capacitor across the output.

\*\* This specification applies only for dc power dissipation permitted by absolute maximum ratings.

**Electrical characteristics MIK78L08A**

Electrical characteristics at specified virtual junction temperature,  $V_i = 14V$ ,  $I_o = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L08A			Units
			Min	Typ	Max	
Output voltage**		25°C	7.7	8	8.3	V
	$I_o = 1mA$ to 40 mA, $V_i = 10.5V$ to 23V	0°C to 125°C	7.6	8	8.4	
	$I_o = 1mA$ to 70mA,		7.6	8	8.4	
Input regulation	$V_i = 10.5V$ to 23V	25°C		42	175	mV
	$V_i = 11V$ to 23V			36	125	
Ripple rejection	$V_i = 13V$ to 23V, $f = 120Hz$	0°C to 125°C	37	46		dB
Output regulation	$I_o = 1mA$ to 100mA	25°C		18	80	μV
	$I_o = 1mA$ to 40mA			10	40	
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		54		mV
Dropout voltage		25°C		1.7		V
Bias current		25°C		4	6	mA
		125°C			5.5	
Bias current change	$V_i = 11V$ to 23V	0°C to 125°C			1.5	
	$I_o = 1mA$ to 40mA				0.1	

**Electrical characteristics MIK78L09A**

Electrical characteristics at specified virtual junction temperature,  $V_i = 16V$ ,  $I_o = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L09A			Units
			Min	Typ	Max	
Output voltage**		25°C	8.6	9	9.4	V
	$I_o = 1mA$ to 40 mA, $V_i = 12V$ to 24V	0°C to 125°C	8.55	9	9.45	
	$I_o = 1mA$ to 70mA,		8.55	9	9.45	
Input regulation	$V_i = 12V$ to 24V	25°C		45	175	mV
	$V_i = 13V$ to 24V			40	125	
Ripple rejection	$V_i = 15V$ to 25V, $f = 120Hz$	0°C to 125°C	38	45		dB
Output regulation	$I_o = 1mA$ to 100mA	25°C		19	90	mV
	$I_o = 1mA$ to 40mA			11	40	
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		58		μV
Dropout voltage		25°C		1.7		V
Bias current		25°C		4.1	6	mA
		125°C			5.5	
Bias current change	$V_i = 13V$ to 24V	0°C to 125°C			1.5	
	$I_o = 1mA$ to 40mA				0.1	

\* Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33μF capacitor across the input and a 0.1μF capacitor across the output.

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**Electrical characteristics MIK78L10A**

Electrical characteristics at specified virtual junction temperature,  $V_I = 17V$ ,  $I_O = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L10A			Units
			Min	Typ	Max	
Output voltage**		25°C	9.6	10	10.4	V
	$I_O = 1mA$ to 40 mA, $V_I = 13V$ to 25V	0°C to 125°C	9.5	10	10.5	
	$I_O = 1mA$ to 70mA,		9.5	10	10.5	
Input regulation	$V_I = 13V$ to 25V	25°C		51	175	mV
	$V_I = 14V$ to 25V			42	125	
Ripple rejection	$V_I = 15V$ to 25V, $f = 120Hz$	0°C to 125°C	37	44		dB
Output regulation	$I_O = 1mA$ to 100mA	25°C		20	90	mV
	$I_O = 1mA$ to 40mA			11	40	
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		62		μV
Dropout voltage		25°C		1.7		V
Bias current		25°C		4.2	6	mA
		125°C			5.5	
Bias current change	$V_I = 14V$ to 25V	0°C to 125°C			1.5	
	$I_O = 1mA$ to 40mA				0.1	

**Electrical characteristics MIK78L12A**

Electrical characteristics at specified virtual junction temperature,  $V_I = 19V$ ,  $I_O = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L12A			Units
			Min	Typ	Max	
Output voltage**		25°C	11.5	12	12.5	V
	$I_O = 1mA$ to 40mA, $V_I = 14V$ to 27V	0°C to 125°C	11.4	12	12.6	
	$I_O = 1mA$ to 70mA		11.4	12	12.6	
Input regulation	$V_I = 14.5V$ to 27V	25°C		55	250	mV
	$V_I = 16V$ to 27V			49	200	
Ripple rejection	$V_I = 15V$ to 25V, $f = 120Hz$	0°C to 125°C	37	42		dB
Output regulation	$I_O = 1mA$ to 100mA	25°C		22	100	mV
	$I_O = 1mA$ to 40mA			13	50	
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		70		μV
Dropout voltage		25°C		1.7		V
Bias current		25°C		4.3	6.5	mA
		125°C			6	
Bias current change	$V_I = 16V$ to 27V	0°C to 125°C			1.5	
	$I_O = 1mA$ to 40mA				0.1	

\* Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33μF capacitor across the input and a 0.1μF capacitor across the output.

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**Electrical characteristics MIK78L15A**

Electrical characteristics at specified virtual junction temperature,  $V_I = 23V$ ,  $I_O = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L15A			Units
			Min	Typ	Max	
Output voltage**		25°C	14.4	15	15.6	V
	$I_O = 1mA$ to 40mA, $V_I = 17.5V$ to 30V	0°C to 125°C	14.25	15	15.75	
	$I_O = 1mA$ to 70mA		14.25	15	15.75	
Input regulation	$V_I = 17.5V$ to 30V	25°C		65	300	mV
	$V_I = 19V$ to 30V			58	250	
Ripple rejection	$V_I = 18.5V$ to 28.5V, $f = 120Hz$	0°C to 125°C	34	39		dB
Output regulation	$I_O = 1mA$ to 100mA	25°C		25	150	mV
	$I_O = 1mA$ to 40mA			15	75	
Output noise voltage	$f = 10Hz$ to 100KHz	25°C		82		μV
Dropout voltage		25°C		1.7		V
Bias current		25°C		4.6	6.5	mA
		125°C			6	
Bias current change	$V_I = 19V$ to 30V	0°C to 125°C			1.5	
	$I_O = 1mA$ to 40mA				0.1	

**Electrical characteristics MIK78L18A**

Electrical characteristics at specified virtual junction temperature,  $V_I = 26V$ ,  $I_O = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L18A			Units
			Min	Typ	Max	
Output voltage**		25°C	17.3	18	18.7	V
	$I_O = 1mA$ to 40mA, $V_I = 20.5V$ to 33V	0°C to 125°C	17.1	18	18.9	
	$I_O = 1mA$ to 70mA		17.1	18	18.9	
Input regulation	$V_I = 20.5V$ to 33V	25°C		70	360	mV
	$V_I = 22V$ to 33V			64	300	
Ripple rejection	$V_I = 21.5V$ to 31.5V, $f = 120Hz$	0°C to 125°C	32	36		dB
Output regulation	$I_O = 1mA$ to 100mA	25°C		27	180	mV
	$I_O = 1mA$ to 40mA			19	90	
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		89		μV
Dropout voltage		25°C		1.7		V
Bias current		25°C		4.7	6.5	mA
		125°C			6	
Bias current change	$V_I = 22V$ to 33V	0°C to 125°C			1.5	
	$I_O = 1mA$ to 40mA				0.1	

\* Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33μF capacitor across the input and a 0.1μF capacitor across the output.

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## Electrical characteristics MIK78L24A

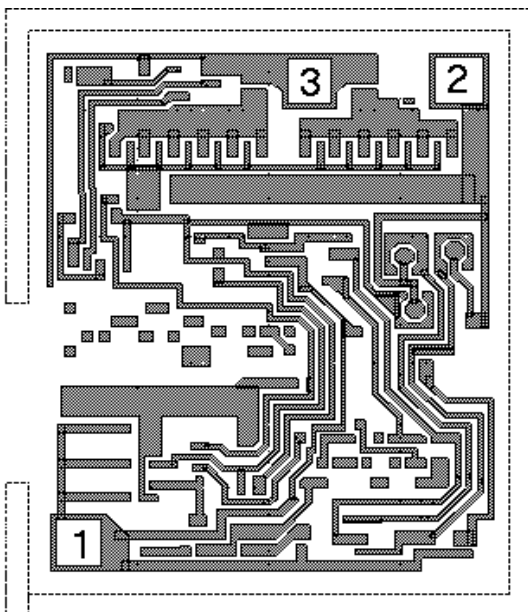
Electrical characteristics at specified virtual junction temperature,  $V_I = 32V$ ,  $I_O = 40mA$  (unless otherwise noted)

Parameter	Test Conditions*		MIK78L24A			Units
			Min	Typ	Max	
Output voltage**		25°C	23	24	25	V
	$I_O = 1mA$ to 40mA, $V_I = 26.5V$ to 39V	0°C to 125°C	22.8	24	25.2	
	$I_O = 1mA$ to 70mA		22.8	24	25.2	
Input regulation	$V_I = 26.5V$ to 39V	25°C		95	480	mV
	$V_I = 29V$ to 39V			78	400	
Ripple rejection	$V_I = 27.5V$ to 37.5V, $f = 120Hz$	0°C to 125°C	30	33		dB
Output regulation	$I_O = 1mA$ to 100mA	25°C		41	240	mV
	$I_O = 1mA$ to 40mA			28	120	
Output noise voltage	$f = 10Hz$ to 100 KHz	25°C		97		μV
Dropout voltage		25°C		1.7		V
Bias current		25°C		4.8	6.5	mA
		125°C			6	
Bias current change	$V_I = 28V$ to 39V	0°C to 125°C			1.5	
	$I_O = 1mA$ to 40mA				0.1	

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## Pad Location MIK78L00



Chip size 1.0 x 1.2 mm

### Pad Location Coordinates

N	Pad Name	Coordinates (μm)	
		X	Y
1	Ground	95	100
2	Input	820	1010
3	Output	535	1015